## INTERNATIONAL SEARCH REPORT

international application No PCT/FR2007/000534

INV.	HO1L21/762				
According to	o international Potent Classification (IPC) or to both national cla	northeation and IDC			
B. FIELDS	SEARCHED				
Minimum de HO1L	ocumentation searched (classification system followed by class	effication symbols)			
Documenta	tion searched other than minimum documentation to the extent	that such documents are included in the fields sea	arched		
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Electronic d	sta base consulted during the international search (name of de	ata base and, where practical, search terms used)			
EPO-In	ternal, INSPEC, PAJ, WPI Data				
C. DOCUMI	ENTS CONSIDERED TO BE RELEVANT  Citation of document, with indication, where appropriate, of it				
Careflory.	Calabili of document, was indication, where appropriate, or it	no rosevani passages	Relevant to claim No.		
A	ALMEIDA ET AL: "Bond formatio	on in ion	1-32		
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	LAUSANNE, CH,				
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X Furth	ter documents are listed in the continuation of Box C.	X See petent family annex.			
<ul> <li>Special or</li> </ul>	ategories of cited documents :	"T" later document published after the Intern	ational filing date		
"A" document defining the general state of the ert which is not considered to be of particular relevance		or priority date and not in conflict with the cited to understand the principle or the invention	ry underlying the		
"E" earlier document but published on or effer the international filing date		"X" document of particular relevance; the cla cannot be considered novel or cannot be	imed invention		
"L" documer which i	nt which may throw doubts on priority claim(s) or is cited to establish the publication date of another	"Y" document of particular relevance: the cla	menits taken alone Imeritayenlen		
	or other special reason (as specified) int referring to an oral disclosure, use, exhibition or	cannot be considered to involve an inve document is combined with one or more ments, such combination being obvious	ntive step when the other such docu-		
	nt published prior to the internetional filing date but an the priority date claimed	in the art.  *&* document member of the same patent is			
	actual completion of the international search	Date of mailing of the international searc			
12 novembre 2007		22/11/2007			
Name and mailing address of the ISA/ European Pateni Office, P.B. 5818 Patentiaan 2		Authorized officer	100		
NL - 2280 HV Rijswijk Tei. (+31-70) 340-2040, Tx, 31 651 epo ni,		Hedouin, Mathias			
om PCT/ISA/2	Fax: (+31-70) 340-3016	iledourii, Platiii as			

## INTERNATIONAL SEARCH REPORT

International application No

PCT/FR2007/000534 C(Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT Category\* Citation of document, with indication, where appropriate, of the relevant passages Relevant to claim No. MATSUO J ET AL: "Abnormal solid solution 1-32 and activation behavior in Ga-implanted Si(100)" APPLIED PHYSICS LETTERS USA. vol. 51, no. 24, 14 December 1987 (1987-12-14), pages 2037-2039, XP002404174 ISSN: 0003-6951 page 2038, column 2 - page 2039, column 2; figures 2-6 JP 58 031519 A (TOKYO SHIBAURA ELECTRIC 1-32 CO) 24 February 1983 (1983-02-24) abstract: figures A-C Α JONES K S ET AL: "Enhanced elimination of 1-32 implantation damage upon exceeding the solid solubility" JOURNAL OF APPLIED PHYSICS USA. vol. 62, no. 10, 15 November 1987 (1987-11-15), pages 4114-4117, XP002404175 ISSN: 0021-8979 cited in the application abstract: figures 1.3

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Patent document cited in search report	Publication date	Τ	Patent family member(s)		Publication date
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